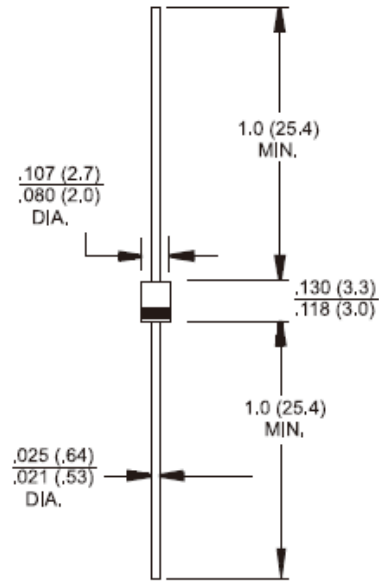


TS-1



Dimensions in inches and (millimeters)



Marking Diagram

- SFT1XG = Specific Device Code
- G = Green Compound
- Y = Year
- M = Work Month

Features

- ◇ High efficiency, low VF
- ◇ High current capability
- ◇ High reliability
- ◇ High surge current capability
- ◇ Low power loss
- ◇ For use in low voltage, high frequency inverter, Free wheeling, and polarity protection application
- ◇ Green compound with suffix "G" on packing code & prefix "G" on datecode

Mechanical Data

- ◇ Case: Molded plastic
- ◇ Epoxy: UL 94V-0 rate flame retardant
- ◇ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ◇ Polarity: Color band denotes cathode
- ◇ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ◇ Mounting position: Any
- ◇ Weight: 0.20 grams

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SFT 11G	SFT 12G	SFT 13G	SFT 14G	SFT 15G	SFT 16G	SFT 17G	SFT 18G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30								A
Maximum Instantaneous Forward Voltage (Note 1) @ 1 A	V_F	0.95			1.3		1.7			V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ $T_A=25^\circ C$	I_R	5								μA
		100								μA
Maximum Reverse Recovery Time (Note 2)	T_{rr}	35								nS
Typical Junction Capacitance (Note 3)	C_j	20				10				pF
Typical Thermal Resistance	$R_{\theta JA}$	100								$^\circ C/W$
Operating Temperature Range	T_J	- 65 to + 150								$^\circ C$
Storage Temperature Range	T_{STG}	- 65 to + 150								$^\circ C$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (SFT11G THRU SFT18G)

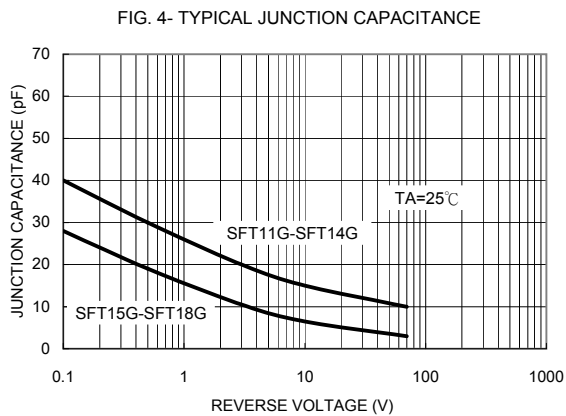
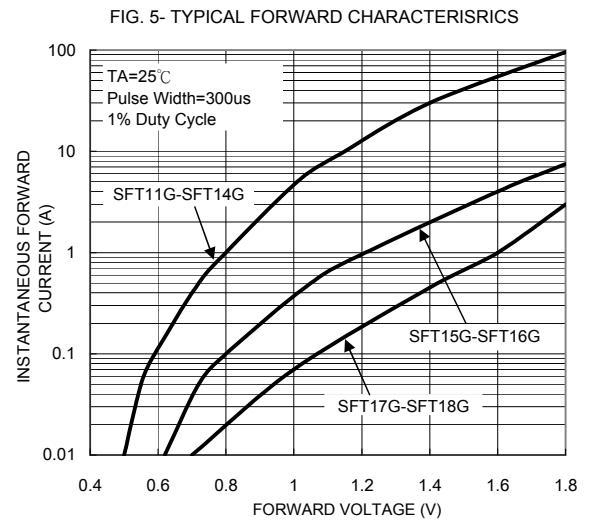
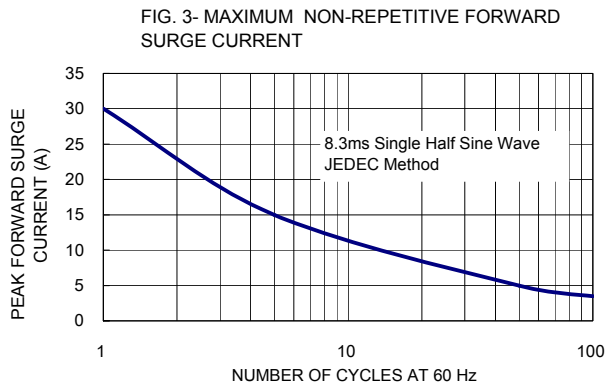
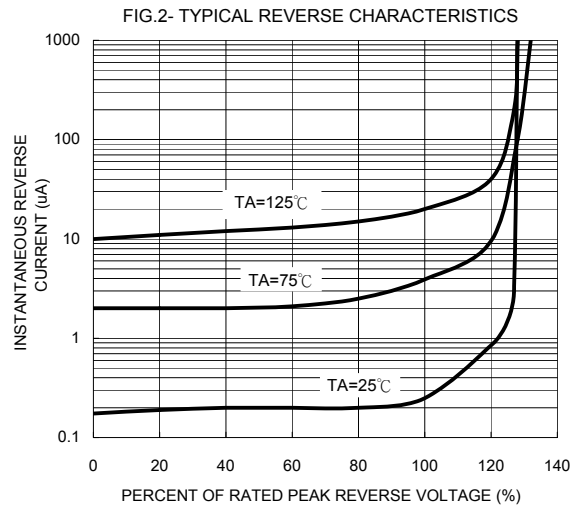
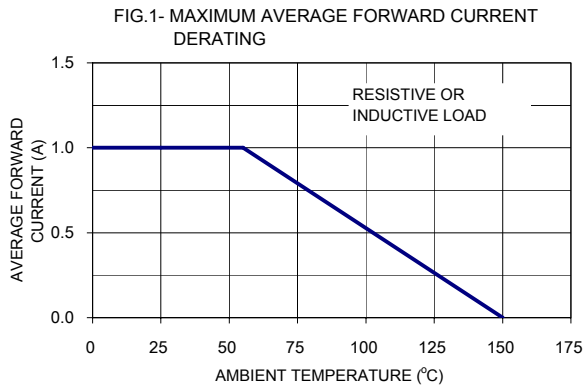


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

